



**TET ESTEL AS**  
ESTONIA

**June**  
**2016**

**Series**  
**T343-500**

**Phase Control Press-Pack**  
**Thyristor**  
**Type T343-500**

Center amplifying gate  
Low on-state and switching losses  
Designed for traction and industrial applications

Maximum mean on-state current	$I_{TAV}$ <b>500 A</b>				
Maximum repetitive peak off-state and reverse voltage	$U_{DRM}$ <b>2000 ÷ 2800 V</b>				
Turn-off time	$U_{RRM}$ <b>200; 250; 320 μs</b>				
$U_{DRM}, U_{RRM}, V$	2000	2200	2400	2600	2800
Voltage code	20	22	24	26	28
$T_{vj}, °C$	- 60 ÷ 125				

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	T343-500	Conditions
$I_{TAV}$	Mean on-state current	A	500 830	$T_c=88 °C$ , $T_c=55 °C$ , 180° half-sine wave, 50 Hz
$I_{TRMS}$	RMS on-state current	A	785	$T_c=88 °C$
$I_{TSM}$	Surge on-state current	kA	10 11	$T_{vj}=125 °C$ $T_{vj}=25 °C$
$I^2t$	Limiting load integral	kA <sup>2</sup> s	500 605	$T_{vj}=125 °C$ $T_{vj}=25 °C$ tp=10 ms Ur=0
$U_{DRM}, U_{RRM}$	Repetitive peak off-state and reverse voltage	V	2000÷2800	$T_j \min \leq T_{vj} \leq T_{jm}$ 180° half-sine wave, 50 Hz Gate open
$U_{DSM}, U_{RSM}$	Non-repetitive peak off-state and reverse voltage	V	2100÷2900	$T_j \min \leq T_{vj} \leq T_{jm}$ 180° half-sine wave tp=10 ms, Single pulse Gate open
$(di_T/dt)_{crit}$	Critical rate of rise of on-state current : non - repetitive repetitive	A/μs	400 200	$T_{vj}=125 °C ; U_D=0,67 U_{DRM}$ , Gate pulse : 10V, 5 Ω, 1 μs rise time, 10 μs
$U_{RGM}$	Peak reverse gate voltage	V	5	$T_j \min \leq T_{vj} \leq T_{jm}$
$T_{stg}$	Storage temperature	°C	-60÷80	
$T_{vj}$	Junction temperature	°C	-60÷125	

**CHARACTERISTICS**

$U_{TM}$	Peak on-state voltage	V	2,2	$T_{vj}=25 °C, I_{TM}=3,14 I_{TAV}$
$U_{T(To)}$	Threshold voltage	V	1,3	$T_{vj}=125 °C$
$R_T$	On-state slope resistance	mΩ	0,65	$1,57 I_{TAV} < I_T < 4,71 I_{TAV}$
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state and reverse current	mA	50 50	$T_{vj}=125 °C$ , $U_D = U_{DRM}$ $U_R = U_{RRM}$

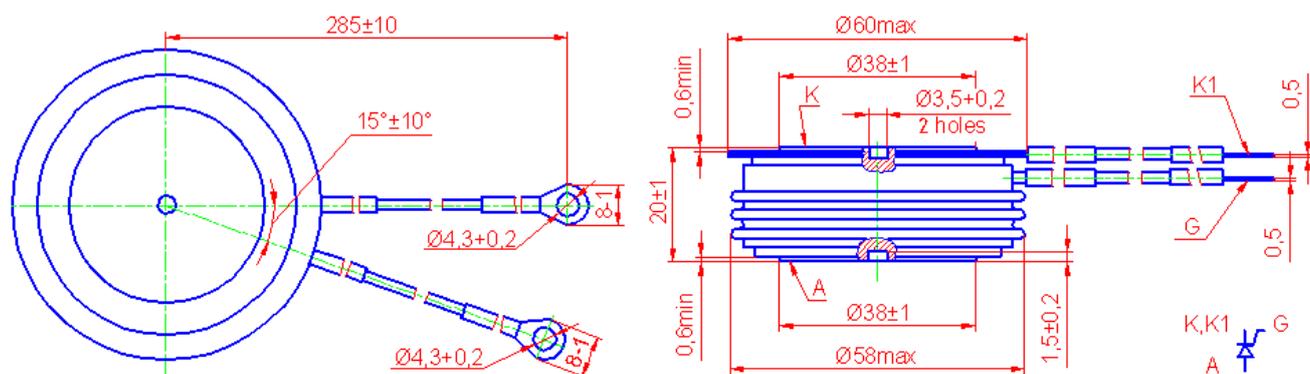
## CHARACTERISTICS

Symbols and parameters		Units	T343-500	Conditions
$I_L$	Latching current	A	1	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$I_H$	Holding current	A	0,6	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}, \text{Gate open}$
$U_{GT}$	Gate trigger direct voltage	V	2,5 5,0	$T_{vj}=25^{\circ}\text{C},$ $T_{vj}=-60^{\circ}\text{C}$
$I_{GT}$	Gate trigger direct current	A	0,3 0,85	$T_{vj}=25^{\circ}\text{C},$ $T_{vj}=-60^{\circ}\text{C}$
$U_{GD}$	Gate non-trigger direct voltage	V	0,25	$T_{vj}=125^{\circ}\text{C}, U_D = 0,67 U_{\text{DRM}}$
$I_{GD}$	Gate non-trigger direct current	mA	10	Direct gate current
$t_{gd}$	Delay time	$\mu\text{s}$	3,2	$T_{vj}=25^{\circ}\text{C}, U_D=500\text{V}$ $I_{\text{TM}} = 500 \text{ A}$
$t_{gt}$	Turn-on time	$\mu\text{s}$	8	Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$t_q$	Turn-off time	$\mu\text{s}$	200÷320	$T_{vj}=125^{\circ}\text{C}, I_{\text{TM}}=500 \text{ A}$ $di_R/dt = 10 \text{ A}/\mu\text{s}, U_R=100\text{V}$ $U_D = 0,67 U_{\text{DRM}}$ $du_D/dt=50 \text{ V}/\mu\text{s}$
$Q_{rr}$	Recovered charge	$\mu\text{C}$	1200	$T_{vj}=125^{\circ}\text{C}, I_{\text{TM}}=500 \text{ A}$ $di_R/dt = 10 \text{ A}/\mu\text{s}, U_R=100\text{V}$
$t_{rr}$	Reverse recovery time	$\mu\text{s}$	22	
$I_{rrm}$	Peak reverse recovery current	A	110	
$(du_D/dt)_{\text{crit}}$	Critical rate of rise of off-state voltage	V/ $\mu\text{s}$	500 1000	$T_{vj}=125^{\circ}\text{C}, U_D = 0,67 U_{\text{DRM}}$ Gate open
$R_{thjc}$	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,032	Direct current, double side cooled

## ORDERING

	T	343	500	28	7	2	
	1	2	3	4	5	6	

- Phase control thyristor.
- Design version.
- Mean on-state current, A.
- Voltage code (28=2800 V).
- Critical rate of rise of off-state voltage (6  $\geq$  500 V/ $\mu\text{s}$ , 7  $\geq$  1000 V/ $\mu\text{s}$ ).
- Group of turn-off time ( $du_D/dt = 50 \text{ V}/\mu\text{s}$ , K2  $\leq$  320 $\mu\text{s}$ , 2  $\leq$  250  $\mu\text{s}$ , P2  $\leq$  200  $\mu\text{s}$ ).



Mounting force : 13÷19 kN  
Weight : 260 grams